Power MOSFET for 1-Cell Lithium-ion Battery Protection 12V, 9.0mΩ, 13A, Dual N-Channel



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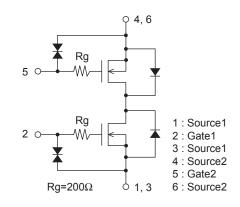
 VSSS
 RSS(on) Max
 IS Max

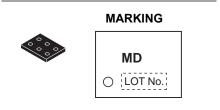
 9.0mΩ@ 4.5V
 9.7mΩ@ 4.0V
 12V

 12V
 10.0mΩ@ 3.8V
 13A

 12.7mΩ@ 3.1V
 17.7mΩ@ 2.5V
 13A

ELECTRICAL CONNECTION N-Channel





ORDERING INFORMATION See detailed ordering and shipping information on page 6 of this data sheet.

This Power MOSFET features a low on-state resistance. This device is suitable for applications such as power switches of portable machines. Best suited for 1-cell lithium-ion battery applications.

Features

- 2.5V drive
- 2kV ESD HBM
- Common-Drain Type
- ESD Diode-Protected Gate
- Pb-Free, Halogen Free and RoHS compliance

Applications

• 1-Cell Lithium-ion Battery Charging and Discharging Switch

SPECIFICATIONS

ABSOLUTE MAXIMUM RATINGS at Ta = 25°C (Note 1)

Parameter	Symbol	Value	Unit
Source to Source Voltage	VSSS	12	V
Gate to Source Voltage	VGSS	±12	V
Source Current (DC)	IS	13	А
Source Current (Pulse) PW≤10µs, duty cycle≤1%	ISP	60	А
Total Dissipation Surface mounted on ceramic substrate $(5000 \text{mm}^2 \times 0.8 \text{mm})$	PT	1.6	W
Junction Temperature	Tj	150	°C
Storage Temperature	Tstg	–55 to +150	°C

Note 1: Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

THERMAL RESISTANCE RATINGS

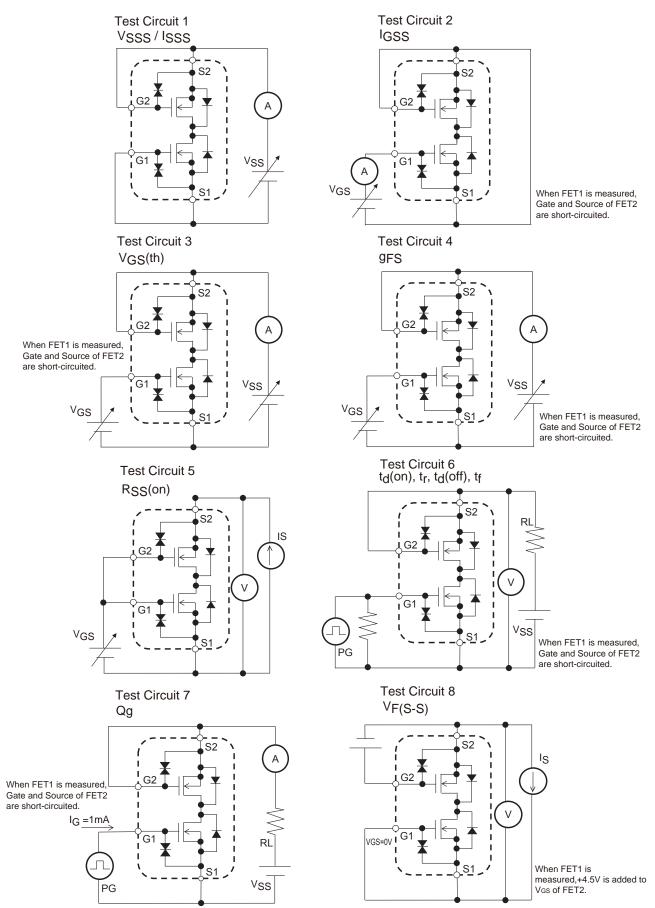
Parameter	Symbol	Value	Unit
Junction to Ambient Surface mounted on ceramic substrate (5000 mm ² × 0.8mm)	R ₀ JA	78.1	°C/W

ELECTRICAL CHARACTERISTICS at Ta = 25°C (Note 2)

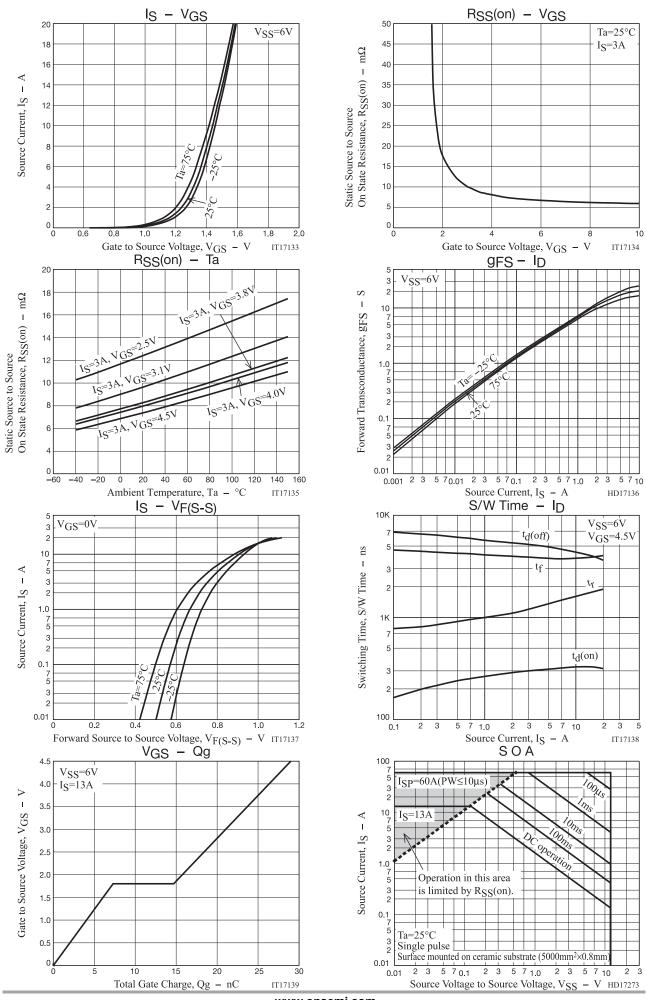
Deventer	Oursels al	Conditions		Ratings			
Parameter	Symbol			min	typ	max	Unit
Source to Source Breakdown Voltage	V(BR)SSS	IS=1mA, VGS=0V	Test Circuit 1	12			v
Zero-Gate Voltage Source Current	ISSS	VSS=10V, VGS=0V	Test Circuit 1			1	μA
Gate to Source Leakage Current	IGSS	VGS=±8V, VSS=0V	Test Circuit 2			±1.0	μA
Gate Threshold Voltage	VGS(th)	VSS=6V, IS=1mA	Test Circuit 3	0.5		1.3	V
Forward Transconductance	9FS	VSS=6V, IS=3A	Test Circuit 4		13.7		S
Static Source to Source On-State Resistance	R _{SS} (on)1	IS=3A, VGS=4.5V	Test Circuit 5	6.0	7.5	9.0	mΩ
	RSS(on)2	IS=3A, VGS=4.0V	Test Circuit 5	6.4	8.1	9.7	mΩ
	RSS(on)3	IS=3A, VGS=3.8V	Test Circuit 5	6.7	8.4	10.0	mΩ
	RSS(on)4	IS=3A, VGS=3.1V	Test Circuit 5	7.8	9.8	12.7	mΩ
	RSS(on)5	IS=3A, VGS=2.5V	Test Circuit 5	10.0	12.6	17.7	mΩ
Turn-ON Delay Time	t _d (on)	VSS=6V, VGS=4.5V, IS=3A Test Circuit 6			300		ns
Rise Time	tr				1200		ns
Turn-OFF Delay Time	t _d (off)				5200		ns
Fall Time	tf				3900		ns
Total Gate Charge	Qg	V _{SS} =6V, V _{GS} =4.5V, I _S =13A Test Circuit 7			29		nC
Forward Source to Source Voltage	VF(S-S)	IS=3A, VGS=0V	Test Circuit 8		0.75	1.2	V

Note 2 : Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

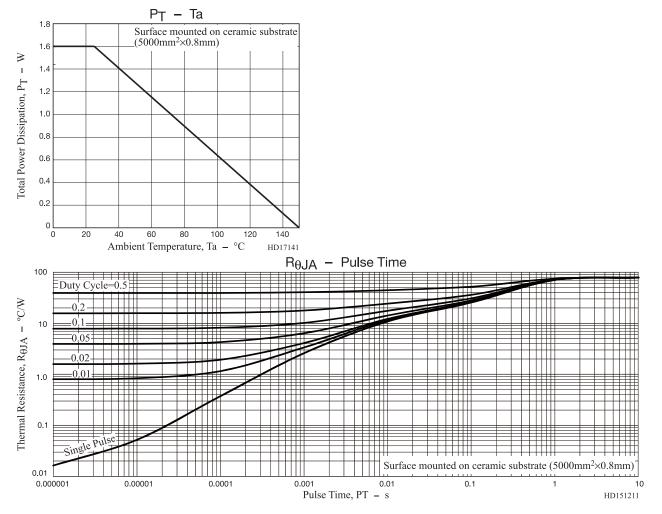
Test circuits are example of measuring FET1 side



When FET2 is measured, the position of FET1 and FET2 is switched.

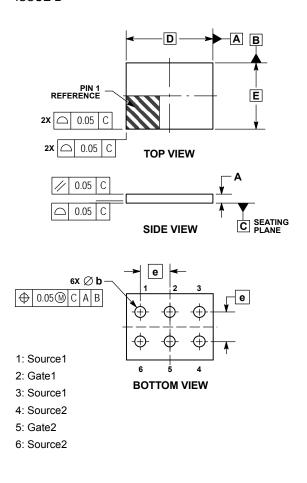


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WLCSP6 1.91x1.46 / EFCP1915-6CE-020 CASE 614AC

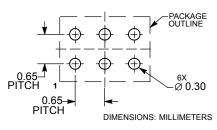
ISSUE B





	MILLIMETERS		
DIM	MIN	MAX	
Α	0.18	0.22	
b	0.27	0.33	
D	1.91 BSC		
E	1.46 BSC		
е	0.65 BSC		

RECOMMENDED SOLDERING FOOTPRINT*



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

ORDERING INFORMATION

Device	Marking	Package	Shipping (Qty / Packing)
EFC6604R-TR	MD	WLCSP6 1.91x1.46 / EFCP1915-6CE-020 (Pb-Free / Halogen Free)	5,000 / Tape & Reel

+ For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D. http://www.onsemi.com/pub link/Collateral/BRD8011-D.PDF

Note on usage : Since the EFC6604R is a MOSFET product, please avoid using this device in the vicinity of highly charged objects. Please contact sales for use except the designated application.

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